

# Mu Wen Chuan

## List of Publications by Year in descending order

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Version: 2024-02-01

18  
papers

84  
citations

1478505

6  
h-index

1474206

9  
g-index

18  
all docs

18  
docs citations

18  
times ranked

57  
citing authors

#	ARTICLE	IF	CITATIONS
1	Device performances analysis of p-type doped silicene-based field effect transistor using SPICE-compatible model. PLoS ONE, 2022, 17, e0264483.	2.5	2
2	Semi-analytical modelling and evaluation of uniformly doped silicene nanotransistors for digital logic gates. PLoS ONE, 2021, 16, e0253289.	2.5	0
3	Impact of phonon scattering mechanisms on the performance of silicene nanoribbon field-effect transistors. Results in Physics, 2021, 29, 104714.	4.1	7
4	Electronic properties and carrier transport properties of low-dimensional aluminium doped silicene nanostructure. Physica E: Low-Dimensional Systems and Nanostructures, 2020, 116, 113731.	2.7	11
5	Electronic properties of graphene nanoribbons with line-edge roughness doped with nitrogen and boron. Physica E: Low-Dimensional Systems and Nanostructures, 2020, 117, 113841.	2.7	9
6	Device performance of silicene nanoribbon field-effect transistor under ballistic transport. , 2020, , .		3
7	Carrier transport of rough-edged doped GNR-FETs with metal contacts at various channel widths. Superlattices and Microstructures, 2020, 143, 106548.	3.1	7
8	Performance metrics of current transport in pristine graphene nanoribbon field-effect transistors using recursive non-equilibrium Green's function approach. Superlattices and Microstructures, 2020, 145, 106624.	3.1	6
9	A review of the top of the barrier nanotransistor models for semiconductor nanomaterials. Superlattices and Microstructures, 2020, 140, 106429.	3.1	11
10	Compact device modelling of interface trap charges with quantum capacitance in MoS <sub>2</sub> -based field-effect transistors. Semiconductor Science and Technology, 2020, 35, 045023.	2.0	4
11	Carrier statistics of highly doped armchair graphene nanoribbons with edge disorder. Superlattices and Microstructures, 2020, 139, 106404.	3.1	3
12	2D Honeycomb Silicon: A Review on Theoretical Advances for Silicene Field-Effect Transistors. Current Nanoscience, 2020, 16, 595-607.	1.2	12
13	Electronic properties of zigzag silicene nanoribbons with single vacancy defect. Indonesian Journal of Electrical Engineering and Computer Science, 2020, 19, 76.	0.8	0
14	Modeling of lightly-doped drain and source contact with boron and nitrogen in graphene nanoribbon. Chinese Journal of Physics, 2019, 62, 258-273.	3.9	3
15	The productiveness of Bootstrap simulator in evaluating the accuracy parameters of measurement system for ball screw. Journal of Physics: Conference Series, 2019, 1366, 012129.	0.4	0
16	Electronic properties of silicene nanoribbons using tight-binding approach. , 2019, , .		2
17	Influence of single vacancy defect at varying length on electronic properties of zigzag graphene nanoribbons. Indonesian Journal of Electrical Engineering and Informatics, 2019, 7, .	0.3	0
18	A low cost spectroscopy with Raspberry Pi for soil macronutrient monitoring. Telkomnika (Telecommunication Computing Electronics and Control), 2019, 17, 1867.	0.8	4